



SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor
- Samsung P/N : CL31C100JHFNFNE
- Description : CAP, 10pF, 630V, ±5%, C0G, 1206

A. Samsung Part Number

		-	<u>CL</u> 31 ①②	<mark>C</mark> 3	<u>100</u> ④	<mark>_</mark> 5	<u>Н</u> 6	<u>Е</u> ⑦	<u>N</u> 8	<u>F</u> 9	<u>N</u> 10	<u>Е</u> 11				
1	Series	Samsung Mi	ulti-layer (Ceram	ic Capa	acito	or									
2	Size	1206 (inc	ch code)		L:	3.2	± 0.1	5	mm		W:	1.6	± 0.15	mm		
3	Dielectric	C0G				8	Inner electrode			Ni						
4	Capacitance	10 pF					Termination			Cu						
5	Capacitance	±5 %					Plating		Sn 10	0%	(Pb Fre	ee)				
	tolerance					9	Product		Product for POWER application			n				
6	Rated Voltage	630 V				10	Spec	Special Reserved f			ved for	r future use				
\bigcirc	Thickness	1.25 ± 0).15 mm			1	Packaging Embossed Type,7"reel(2,000ea)			a)						

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1⊮±10% 0.5~5Vrms					
Q	600 min						
Insulation	More than 500Mohm⋅ <i>μ</i> F	500±50 Vdc 60~120 sec.					
Resistance							
Appearance	No abnormal exterior appearance	Visual inspection					
Withstanding	No dielectric breakdown or	150% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	C0G						
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±30PPM/℃)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change : within ±0.5pF	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120 $^\circ C$ for 10~30sec.)					
Resistance to	Capacitance change : within ±0.25pF	Solder pot : 270±5℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition					
Vibration Test	Capacitance change : within ±0.25pF	Amplitude : 1.5mm					
	Tan δ, IR : initial spec.	From $10Hz$ to $55Hz$ (return : 1min.)					
		2hours \times 3 direction (x, y, z)					
Moisture	Capacitance change : within ±0.75pF	With rated voltage					
Resistance	Q : 133.33 min	40±2℃, 90~95%RH, 500 +12/-0 hours					
	IR : More than $25M\Omega \cdot \mu F$						
High Temperature	Capacitance change : within ±0.3pF	With 120% of the rated voltage					
Resistance	Q : 300 min	Max. operating temperature					
	IR : More than $50M\Omega \cdot \mu F$	1000+48/-0 hours					
Temperature	Capacitance change : within ±0.25pF	1 cycle condition					
Cycling	Tan δ, IR : initial spec.	Min. operating temperature \rightarrow 25 °C					
		\rightarrow Max. operating temperature \rightarrow 25 °C					
		5 cycles test					

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5°C, 10sec. Max)

* For the more detail Specification, Please refer to the Samsung MLCC catalogue.